

Electronic Acknowledgement Receipt

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International Application Number:	
Confirmation Number:	7331
Title of Invention:	Solution-based fabrication of photovoltaic cell
First Named Inventor/Applicant Name:	Dong Yu
Customer Number:	27652
Filer:	Hao Y. Tung
Filer Authorized By:	
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Application Type:	Utility under 35 USC 111(a)

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Payment was successfully received in RAM	\$ 180
RAM confirmation Number	4539
Deposit Account	
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File Listing:

Document Number	Document Description	File Name	File Size(Bytes) /Message Digest	Multi Part /.zip	Pages (if appl.)
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1	Information Disclosure Statement (IDS) Filed	NSL-029_IDS_040208.pdf	128469 43bc8554a39496e553b0a91ab04aac 2a124e9c4	no	7
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This is not an USPTO supplied IDS fillable form					
2	Foreign Reference	refAR_DE2741954.pdf	140507 770ea444c768f2aa0a07f912d4d4f0a907 ddda457b	no	7
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3	Foreign Reference	refAS_EP793277.pdf	3321900 9dc819ed34173456708708a21205e4f3 009d0c5b	no	58
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7	Foreign Reference	refAW_WO03007386.pdf	833367 1ec5c0e0221670305a320bec28b4fa137f a11405	no	18
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9	NPL Documents	Ref_AY_Non-vacuum-proce ssing.PDF	362877 bfb44ba3eb6046de231807a7a6edf773d eda9576	no	5

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12	NPL Documents	Ref_BB_CuInSe2-films-prepared-by-screen-printing-and-selective-interdiffusion-method.PDF	375611 72995dd22960f16e0dd5661d897952700797e1	no	6
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If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.

New International Application Filed with the USPTO as a Receiving Office

If a new international application is being filed and the international application includes the necessary components for an international filing date (see PCT Article 11 and MPEP 1810), a Notification of the International Application Number and of the International Filing Date (Form PCT/RO/105) will be issued in due course, subject to prescriptions concerning national security, and the date shown on this Acknowledgement Receipt will establish the international filing date of the application.